Product data sheet

1. General description

NPN Resistor-Equipped Transistor (RET) in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

PNP complement: PDTB143EU

2. Features and benefits

- 500 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- ± 10 % resistor ratio tolerance
- High temperature applications up to 175 °C
- AEC-Q101 qualified

3. Applications

- Controlling IC inputs
- Cost-saving alternative to BC817 series in digital applications
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	500	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		0.9	1	1.1	



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	□ 3	
2	GND	ground (emitter)		R1 P
3	0	output (collector)	SC-70 (SOT323)	GND sym007

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PDTD143EU	SC-70	plastic, surface-mounted package; 3 leads; 1.3 mm pitch; 2 mm x 1.25 mm x 0.95 mm body	SOT323		

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PDTD143EU	ZT%

[1] % = placeholder for manufacturing site code

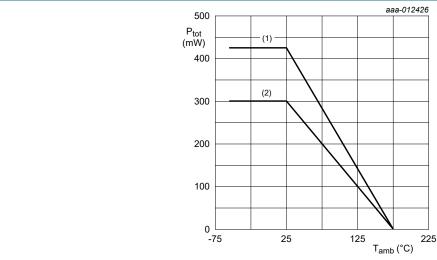
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	10	V
VI	input voltage			-10	30	V
Io	output current			-	500	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
			[2]	-	425	mW
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-55	175	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.



- (1) FR4 PCB, 4-layer copper, standard footprint
- (2) FR4 PCB, single-sided copper, tin-plated and standard footprint

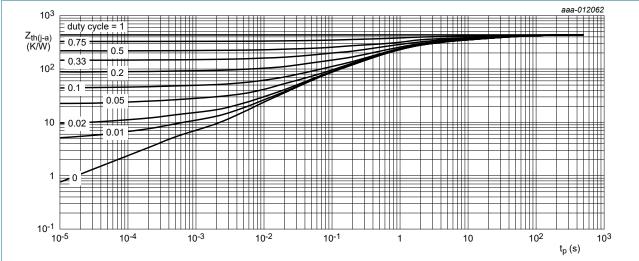
Fig. 1. Power derating curves

9. Thermal characteristics

Table 6. Thermal characteristics

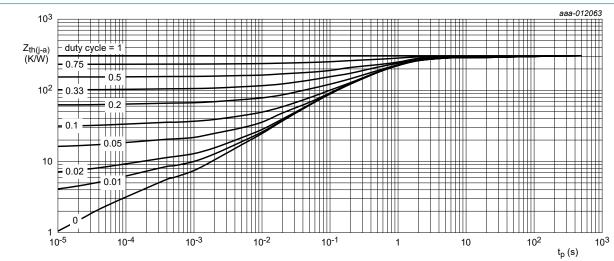
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
""(J-"a)	thermal resistance from	in free air	[1]	-	-	500	K/W
junction to ambient		[2]	-	-	353	K/W	

- [1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.



FR4 PCB, single-sided copper, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT323/SC-70; typical values



FR4 PCB, 4-layer copper, tin-plated and standard footprint.

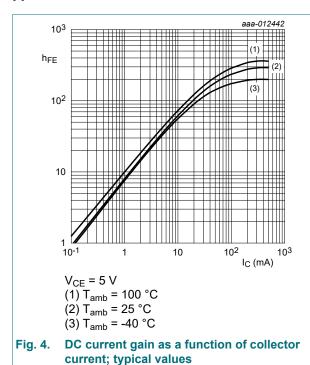
Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT323/SC-70; typical values

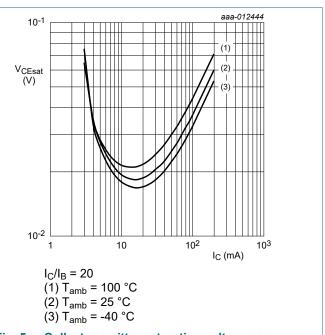
10. Characteristics

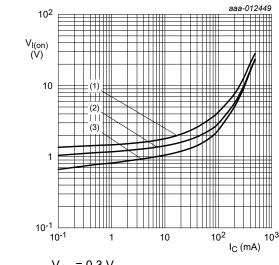
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = 40 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	current	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
I _{CEO}	collector-emitter cut-off current	V _{CE} = 50 V; I _B = 0 A; T _{amb} = 25 °C		-	-	0.5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	0.9	mA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 50 mA; T _{amb} = 25 °C		60	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}; T_{amb} = 25 \text{ °C}$		-	-	100	mV
V _{I(off)}	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		0.6	0.9	1.5	V
V _{I(on)}	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 20 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		1	1.6	2.2	V
R1	bias resistor 1 (input)			3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio			0.9	1	1.1	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	7	-	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 50 mA; f = 100 MHz; T_{amb} = 25 °C	[1]	-	225	-	MHz

[1] Characteristics of built-in transistor.







V_{CE} = 0.3 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Fig. 6. On-state input voltage as a function of collector | Fig. 7. current; typical values

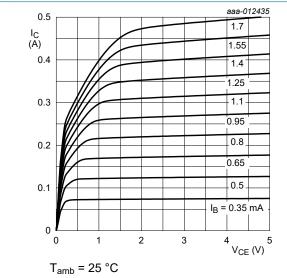
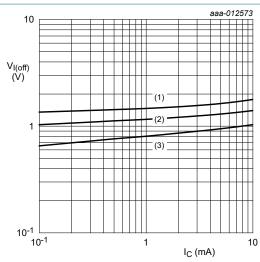
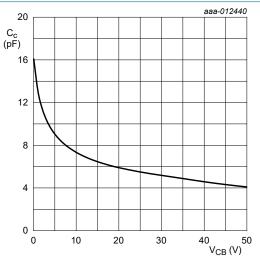


Fig. 8. Collector current as a function of collectoremitter voltage; typical values



V_{CE} = 5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

Off-state input voltage as a function of collector current; typical values

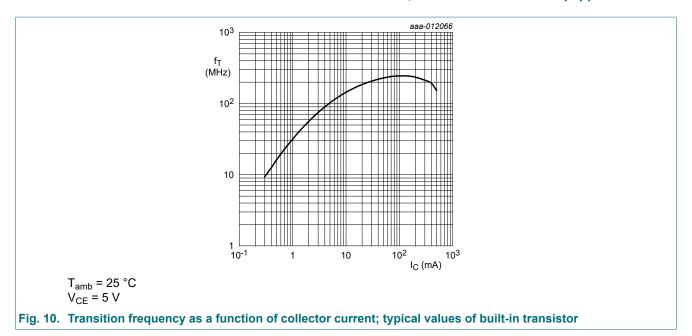


f = 1 MHz $T_{amb} = 25 \, ^{\circ}C$

Fig. 9. Collector capacitance as a function of collectorbase voltage; typical values

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50 V, 500 mA NPN resistor-equipped transistor

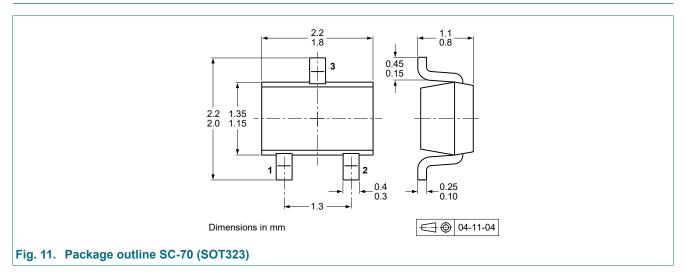


11. Test information

Quality information

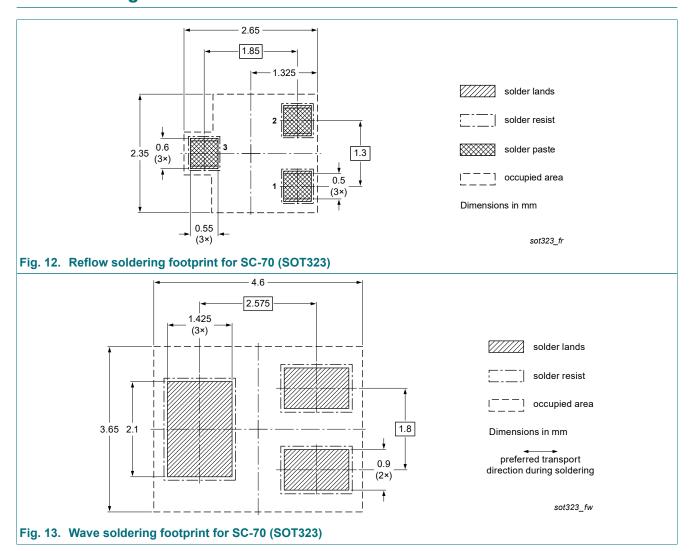
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	ate Data sheet status Change notice		Supersedes					
PDTD143EU v.2	20240417	Product data sheet	-	PDTD1XXXU_SER v.1					
Modifications:	Family data sheet re	Family data sheet reduced to single type data sheet.							
PDTD1XXXU_SER v.1	20140513	Product data sheet	-	-					

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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